

KBU10A THRU KBU10M

Single Phase 10 AMPS. Silicon Bridge Rectifiers

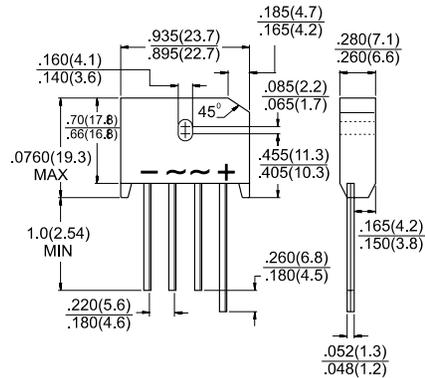


Voltage Range
50 to 1000 Volts
Current
10.0 Amperes

KBU

Features

- ✧ UL Recognized
- ✧ High surge current capability
- ✧ Ideal for printed circuit board
- ✧ Reliable low cost construction technique results in inexpensive product
- ✧ High temperature soldering guaranteed: 250°C / 10 seconds / 0.375" (9.5mm) lead length at 5 lbs., (2.3 kg) tension
- ✧ Weight: 8 grams



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	KBU 10A	KBU 10B	KBU 10D	KBU 10G	KBU 10J	KBU 10K	KBU 10M	Units
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @ T _A = 55°C	10.0							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	300							A
Maximum Instantaneous Forward Voltage @ 10A	1.1							V
Maximum DC Reverse Current @ T _A =25°C at Rated DC Blocking Voltage @ T _A =100°C	10 500							uA uA
Typical Thermal Resistance (Note) R θ JC	2.2							°C/W
Operating Temperature Range T _J	-55 to +125							°C
Storage Temperature Range T _{STG}	-55 to +150							°C

Note: Thermal Resistance from Junction to Case with Device Mounted on 100mm x 100mm x 1.6mm Cu Plate Heatsink.



RATINGS AND CHARACTERISTIC CURVES (KBU10A THRU KBU10M)

FIG.1- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER BRIDGE ELEMENT

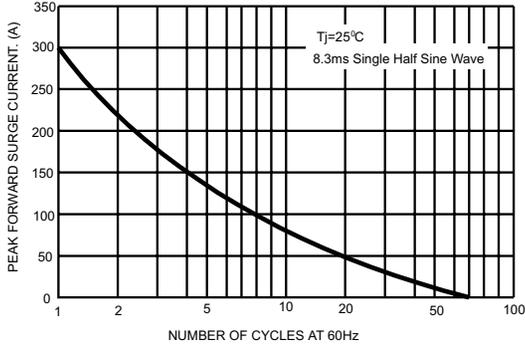


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE

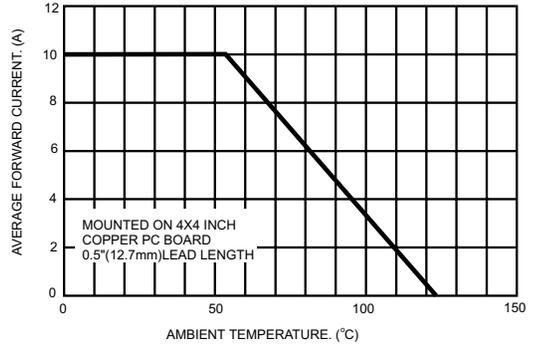


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER BRIDGE ELEMENT

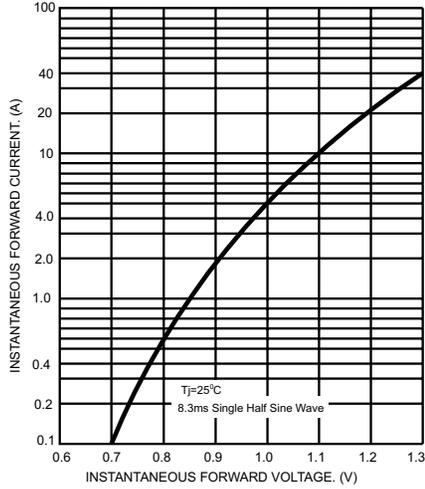


FIG.4- TYPICAL REVERSE CHARACTERISTICS PER BRIDGE ELEMENT

